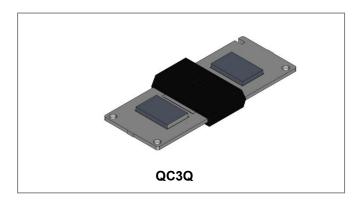






GF4045TS-1 Power Modules Schottky Rectifier



Mechanical Data

- Case: QC3Q
- High temperature soldering guaranteed
 Heated-tool welding 260℃,10 seconds
- Marking Code: GF4045TS-1

Features

- Low thermal resistance
- Lower forward voltage drop, low power loss
- Isolate Package design, ideal for heat dispersion
- · High forward current capability
- Trench MOS Schottky technology
- Excellent anti-humidity
- Low profile package
- · High forward surge capability
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V
Average Rectified Forward Current	I _{F (AV)}	Tc=110°C, In DC	40	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T _J = 25 °C	350	Α
Rating for fusing (t<8.3ms)	l²t	T _J = 25 °C	500	A ² sec

Electrical Characteristics

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 40A, Pulse, T _J = 25 °C	0.48	0.52	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.03	0.20	mA
	I _{R2}	@V _R = rated V _R T _J = 100 °C	-	12	mA
	I _{R3}	@V _R = rated V _R T _J = 125 °C	26	55	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	5840	-	pF

^{*} Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com
 sales@ smc-diodes.com



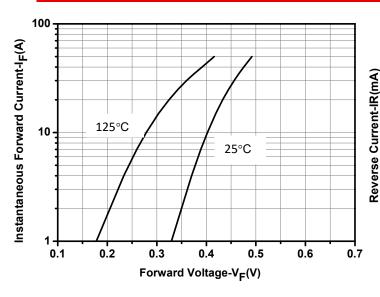




Thermal-Mechanical Specifications

Characteristics	naracteristics Symbol		Specification	Units
Junction Temperature	TJ	IN DC Forward Mode, without reverse bias, t ≤1 h	-55 to +200	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	-	1.5	°C/W

Ratings and Characteristics Curves



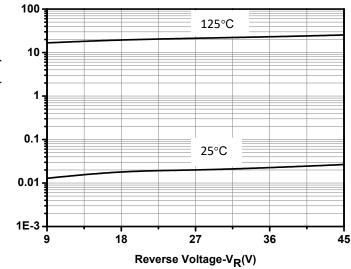


Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics

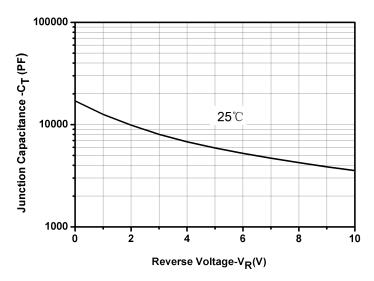


Fig.3-Capacitance vs. Reverse Voltage

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •



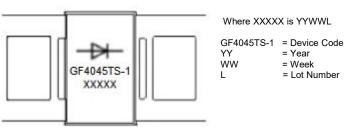




Ordering Information

Device	Package	Shipping
GF4045TS-1	QC3Q	32pcs/Tube

Marking Diagram



Order P/N	Terminals	Additional	0 20
GF4045TS-1-S1	Tin Plated	None	Solder F
GF4045TS-1-S2	Tin Plated	Solder Paste ⊏	Solder P
GF4045TS-1-S3	Tin Plated	Solder Block	
GF4045TS-1-N1	Nickel Plated	None	
GF4045TS-1-N2	Nickel Plated	Solder Paste	Solder B
GF4045TS-1-N3	Nickel Plated	Solder Block ⊏	

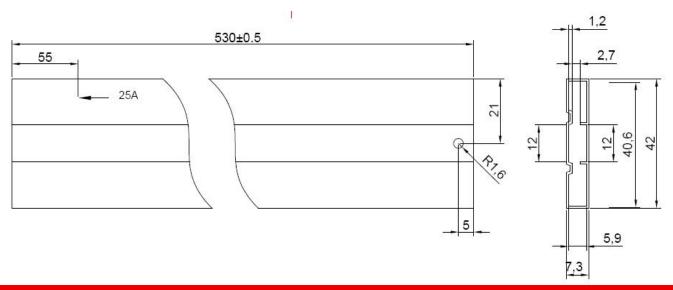
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •



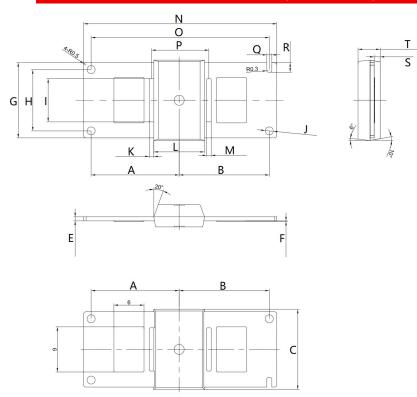




Tube Specification QC3Q (Millimeters)



Mechanical Dimensions QC3Q (Millimeters)



Symbol	Dimensions in millimeters			
	Min.	Typical	Max	
Α		17.54		
В		17.96		
С	15.90	16.00	16.10	
E	0.77	0.80	0.83	
F	0.08	0.10	0.12	
G	14.90	15.00	15.10	
Н	12.15	12.20	12.25	
I	8.55	8.60	8.65	
J		1.60	1.70	
K	0.86	0.90	0.93	
L	10.00	10.10	10.20	
M	0.87	0.90	0.93	
N	38.40	38.50	38.60	
0	35.45	35.50	35.55	
Р	11.32	11.42	11.52	
Q		1.00	1.10	
R		1.90	2.00	
S	1.15	1.20	1.25	
Т	4.30	4.40	4.50	

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •







DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..